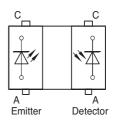


Reflective Optical Sensor with PIN Photodiode Output

Description

TCND5000 is a reflective sensor SMD in plastic package including IR emitter and PIN Photodiode. Optical axes of emitter and detector are parallel aligned for reflective operation. Sensor includes IR filter and cross talk barrier.



Features

- Operating distance 2 mm to 40mm
- SMD
- · High intensity IR emitter, 950 mm
- · High light to voltage linearity
- High sensitivity PIN Photodiode
- · IR band pass filter
- · Crosstalk barrier
- · Tape and reel
- Dry Pack
- JEDEC Level 4
- Lead-free component
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC

Applications

Proximity sensor Object sensor Motion sensor

Parts Table

Part	Remarks		
TCND5000	MOQ: 2000 pc		

Absolute Maximum Ratings

Input (Emitter)

Parameter	Test condition	Symbol	Value	Unit
Reverse Voltage		V _R	5	V
Forward current		I _F	100	mA
Peak Forward Current	$t_p = 50 \mu s$, $T = 2 ms$, $T_{amb} = 25 °C$	I _{FM}	500	mA
Power Dissipation		P _V	190	mW
Junction Temperature		Tj	100	°C

Output (Detector)

Parameter	Test condition	Symbol Value		Unit
Reverse Voltage		V_{R}	60	V
Power Dissipation		P _V	75	mW
Junction Temperature		T _j	100	°C

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TCND5000

Vishay Semiconductors



Sensor

Parameter	Test condition	Symbol	Value	Unit
Operating Temperature Range		T _{amb}	- 40 to + 85	°C
Storage Temperature Range		T _{stg}	- 40 to + 100	°C

Electrical Characteristics

Input (Emitter)

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Forward Voltage	$I_F = 20 \text{ mA}, t_p = 20 \text{ ms}$	V _F		1.2	1.5	V
Temp. Coefficient of V _F	I _F = 1 mA	TK _{VF}		- 1.3		mV/K
Reverse Current	V _R = 5 V	I _R			10	μΑ
Junction capacitance	V _R = 0 V, f = 1 MHz, E = 0	C _j		25		pF
Radiant Intensity	$I_F = 20 \text{ mA}, t_p = 20 \text{ ms}$	I _e		7		mW/sr
Angle of Half Intensity		φ		±12		deg
Peak Wavelength	I _F = 100 mA	λ_{p}		950		nm
Spectral Bandwidth	I _F = 100 mA	Δλ		50		nm
Temp. Coefficient of λ_p	I _F = 100 mA	TK _{λp}		0.2		nm/K
Rise Time	I _F = 100 mA	t _r		800		ns
Fall Time	I _F = 100 mA	t _f		800		ns

see figures 2 to 8 accordingly

Output (Detector)

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Forward Voltage	I _F = 50 mA	V _F		1.0	1.3	V
Breakdown Voltage	I _R = 100 μA	V _{BR}	60			V
Reverse Dark Current	V _R = 10 V, E = 0	I _{ro}		1	10	nA
Diode capacitance	V _R = 5 V, f = 1 MHz, E = 0	C _D		1.8		pF
Reverse Light Current	$E_e = 1 \text{ mW/cm}^2$ $\lambda = 950 \text{nm}, V_R = 5 \text{ V}$	I _{ra}		12		μΑ
Temp. Coefficient of I _{ra}	$V_R = 5 \text{ V}, \ \lambda = 870 \text{ nm}$	TK _{ira}		0.2		%/ K
Angle of Half Intensity		φ		± 15		٥
Wavelength of Peak Sensitivity		λ_{p}		900		nm
Range of Spectral Bandwidth		λ _{0.5}		840 to 1050		nm
Rise Time	$V_R = 10 \text{ V}, R_L = 50 \Omega,$ $\lambda = 820 \text{ nm}$	t _r		4		ns
Fall Time	$V_R = 10 \text{ V}, R_L = 50 \Omega,$ $\lambda = 820 \text{ nm}$	t _f		4		ns

see figures 7 to 12 accordingly

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Sensor

 T_{amb} = 25 °C, unless otherwise specified

Parameter	Test condition	Symbol	Min	Тур.	Max	Unit
Reverse Light Current	$V_R = 2.5 \text{ V}, I_F = 20 \text{ mA}$ d = 30 mm reflective mode: see figure 1	I _{ra}	110			nA

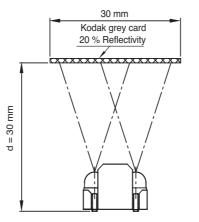


Figure 1. Test Circuit

Typical Characteristics (T_{amb} = 25 °C unless otherwise specified)

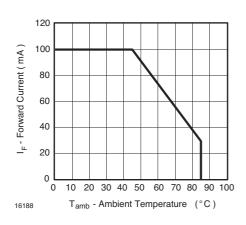
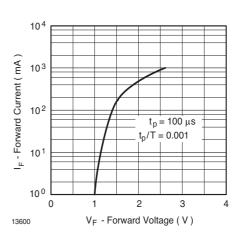


Figure 2. Forward Current vs. Ambient Temperature



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Figure 3. Forward Current vs. Forward Voltage



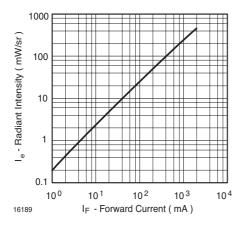


Figure 4. Radiant Intensity vs. Forward Current

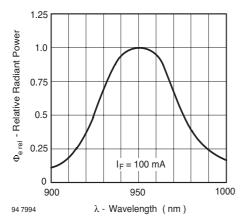


Figure 5. Relative Radiant Power vs. Wavelength

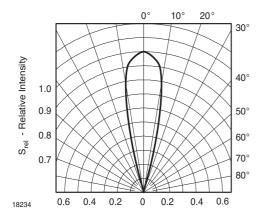


Figure 6. Relative Radiant Intensity vs. Angular Displacement

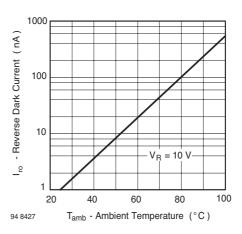


Figure 7. Reverse Dark Current vs. Ambient Temperature

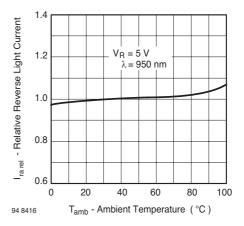


Figure 8. Relative Reverse Light Current vs. Ambient Temperature

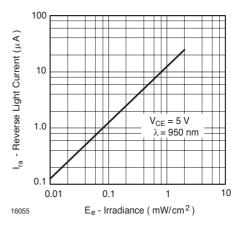


Figure 9. Reverse Light Current vs. Irradiance



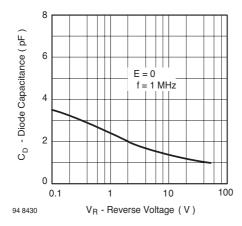


Figure 10. Diode Capacitance vs. Reverse Voltage



Figure 13. Relative Reverse Current vs. Distance

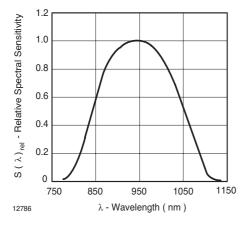


Figure 11. Relative Spectral Sensitivity vs. Wavelength

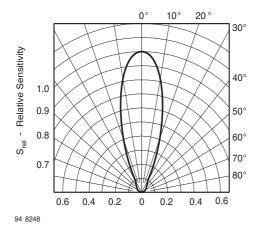
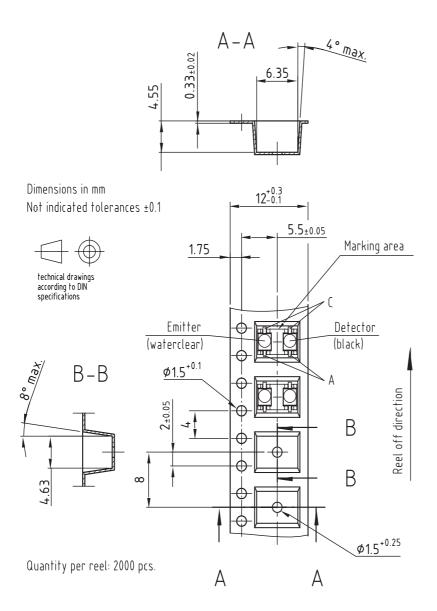


Figure 12. Relative Radiant Sensitivity vs. Angular Displacement

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Taping



Material of Blistertape: PC black Sealing of cavities with hot sealing cover tape, C-Pak Type CP - 2010 AS (Thickness: 0.055 - 0.075mm; Base Material: Polyester)

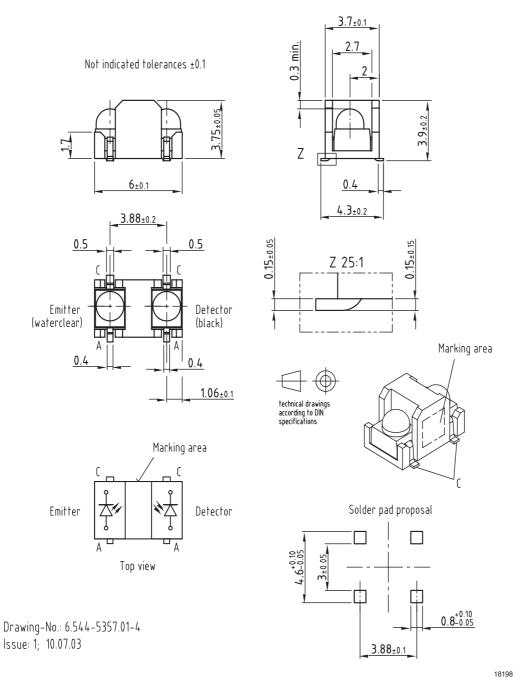
Drawing-No.: 9.700-5281.01-4

Issue: 3; 23.09.03

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Package Dimensions in mm



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Precautions For Use

1. Over-current-proof

Customer must apply resistors for protection, otherwise slight voltage shift will cause big current change (Burn out will happen).

2. Storage

- 2.1 Storage temperature and rel. humidity conditions are: 5°C to 30°C, R.H. 60%
- 2.2 Floor life must not exceed 72 h, acc. to JEDEC level 4, J-STD-020.

Once the package is opened, the products should be used within 72 h. Otherwise, they should be kept in a damp proof box with desiccant.

Considering tape life, we suggest to use products within one year from production date.

- 2.3 If opened more than 72 h in an atmosphere 5°C to 30°C, R.H. 60%, devices should be treated at 60°C \pm 5°C for 15 hrs.
- 2.4 If humidity indicator in the package shows pink color (normal blue), then devices should be treated with the same conditions as 2.3

Reflow Solder Profiles

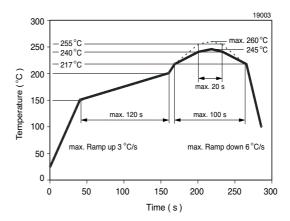


Figure 14. Lead-Free Reflow Solder Profile

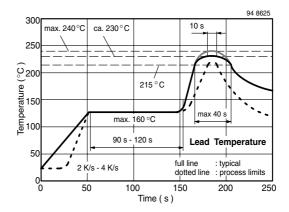


Figure 15. Lead Tin (SnPb) Reflow Solder Profile



Ozone Depleting Substances Policy Statement

It is the policy of Vishay Semiconductor GmbH to

- 1. Meet all present and future national and international statutory requirements.
- 2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

- 1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
- 2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
- 3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use Vishay Semiconductors products for any unintended or unauthorized application, the buyer shall indemnify Vishay Semiconductors against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

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